

MUN2111T1 Series

Preferred Devices

Bias Resistor Transistors

PNP Silicon Surface Mount Transistors with Monolithic Bias Resistor Network

This new series of digital transistors is designed to replace a single device and its external resistor bias network. The Bias Resistor Transistor (BRT) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base-emitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space. The device is housed in the SC-59 package which is designed for low power surface mount applications.

Features

- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- Moisture Sensitivity Level: 1
- ESD Rating – Human Body Model: Class 1
– Machine Model: Class B
- The SC-59 Package Can be Soldered Using Wave or Reflow
- The Modified Gull-Winged Leads Absorb Thermal Stress During Soldering Eliminating the Possibility of Damage to the Die
- Pb-Free Packages are Available

MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Rating	Symbol	Value	Unit
Collector – Base Voltage	V_{CBO}	50	Vdc
Collector – Emitter Voltage	V_{CEO}	50	Vdc
Collector Current	I_C	100	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	230 (Note 1) 338 (Note 2) 1.8 (Note 1) 2.7 (Note 2)	mW $^\circ\text{C/W}$
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	540 (Note 1) 370 (Note 2)	$^\circ\text{C/W}$
Thermal Resistance, Junction-to-Lead	$R_{\theta JL}$	264 (Note 1) 287 (Note 2)	$^\circ\text{C/W}$
Junction and Storage Temperature Range	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$

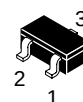
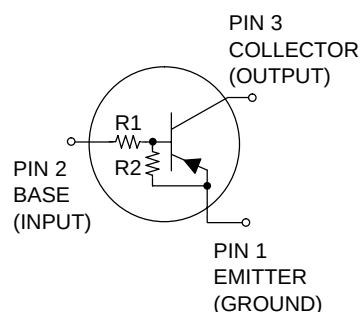
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. FR-4 @ Minimum Pad.
2. FR-4 @ 1.0 x 1.0 inch Pad.



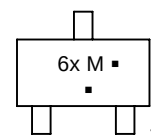
ON Semiconductor®

<http://onsemi.com>



SC-59
CASE 318D
PLASTIC

MARKING DIAGRAM



6x = Specific Device Code
M = Date Code*
■ = Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

DEVICE MARKING INFORMATION

See device marking table on page 2 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

MUN2111T1 Series

DEVICE MARKING AND RESISTOR VALUES

Device	Package	Marking	R1 (K)	R2 (K)	Shipping [†]
MUN2111T1	SC-59	6A	10	10	3000 / Tape & Reel
MUN2111T1G	SC-59 (Pb-Free)	6A	10	10	
MUN2111T3G	SC-59 (Pb-Free)	6A	10	10	10,000 / Tape & Reel
MUN2112T1	SC-59	6B	22	22	3000 / Tape & Reel
MUN2112T1G	SC-59 (Pb-Free)	6B	22	22	
MUN2113T1	SC-59	6C	47	47	
MUN2113T1G	SC-59 (Pb-Free)	6C	47	47	
MUN2114T1	SC-59	6D	10	47	
MUN2114T1G	SC-59 (Pb-Free)	6D	10	47	
MUN2115T1 (Note 3)	SC-59	6E	10	∞	
MUN2115T1G (Note 3)	SC-59 (Pb-Free)	6E	10	∞	
MUN2116T1 (Note 3)	SC-59	6F	4.7	∞	
MUN2116T1G (Note 3)	SC-59 (Pb-Free)	6F	4.7	∞	
MUN2130T1 (Note 3)	SC-59	6G	1.0	1.0	
MUN2130T1G (Note 3)	SC-59 (Pb-Free)	6G	1.0	1.0	
MUN2131T1 (Note 3)	SC-59	6H	2.2	2.2	
MUN2131T1G (Note 3)	SC-59 (Pb-Free)	6H	2.2	2.2	
MUN2132T1 (Note 3)	SC-59	6J	4.7	4.7	
MUN2132T1G (Note 3)	SC-59 (Pb-Free)	6J	4.7	4.7	
MUN2133T1 (Note 3)	SC-59	6K	4.7	47	
MUN2133T1G (Note 3)	SC-59 (Pb-Free)	6K	4.7	47	
MUN2134T1 (Note 3)	SC-59	6L	22	47	
MUN2134T1G (Note 3)	SC-59 (Pb-Free)	6L	22	47	
MUN2136T1	SC-59	6N	100	100	
MUN2136T1G	SC-59 (Pb-Free)	6N	100	100	
MUN2137T1	SC-59	6P	47	22	
MUN2137T1G	SC-59 (Pb-Free)	6P	47	22	
MUN2140T1 (Note 3)	SC-59	6T	47	∞	
MUN2140T1G (Note 3)	SC-59 (Pb-Free)	6T	47	∞	

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

3. New resistor combinations. Updated curves to follow in subsequent data sheets.

MUN2111T1 Series

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS					
Collector–Base Cutoff Current ($V_{CB} = 50\text{ V}$, $I_E = 0$)	I_{CBO}	–	–	100	nAdc
Collector–Emitter Cutoff Current ($V_{CE} = 50\text{ V}$, $I_B = 0$)	I_{CEO}	–	–	500	nAdc
Emitter–Base Cutoff Current ($V_{EB} = 6.0\text{ V}$, $I_C = 0$)	I_{EBO}	–	–	0.5	mAdc
MUN2111T1		–	–	0.2	
MUN2112T1		–	–	0.1	
MUN2113T1		–	–	0.2	
MUN2114T1		–	–	0.9	
MUN2115T1		–	–	1.9	
MUN2116T1		–	–	4.3	
MUN2130T1		–	–	2.3	
MUN2131T1		–	–	1.5	
MUN2132T1		–	–	0.18	
MUN2133T1		–	–	0.13	
MUN2134T1		–	–	0.05	
MUN2136T1		–	–	0.13	
MUN2137T1		–	–	0.20	
MUN2140T1		–	–		
Collector–Base Breakdown Voltage ($I_C = 10\text{ }\mu\text{A}$, $I_E = 0$)	$V_{(BR)CBO}$	50	–	–	Vdc
Collector–Emitter Breakdown Voltage (Note 4) ($I_C = 2.0\text{ mA}$, $I_B = 0$)	$V_{(BR)CEO}$	50	–	–	Vdc

ON CHARACTERISTICS (Note 4)[illegible]

4. Pulse Test: Pulse Width < 300 μ s, Duty Cycle < 2.0%.

MUN2111T1 Series

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
ON CHARACTERISTICS (Note 4)					
Output Voltage (off) (V _{CC} = 5.0 V, V _B = 0.5 V, R _L = 1.0 kΩ) (V _{CC} = 5.0 V, V _B = 0.050 V, R _L = 1.0 kΩ) (V _{CC} = 5.0 V, V _B = 0.25 V, R _L = 1.0 kΩ) <					

4. Pulse Test: Pulse Width < 300 μs, Duty Cycle < 2.0%.

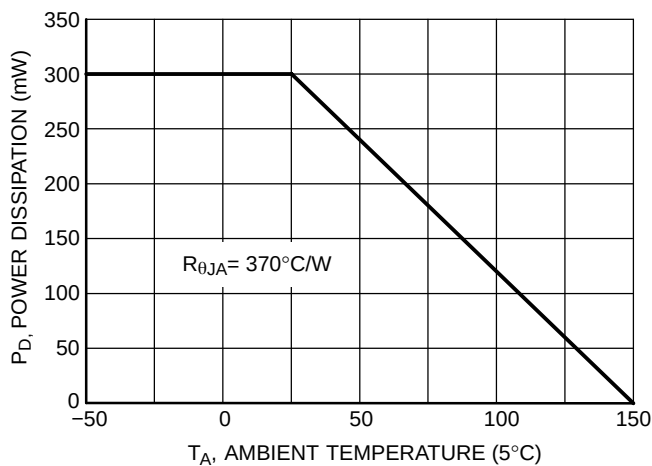


Figure 1. Derating Curve

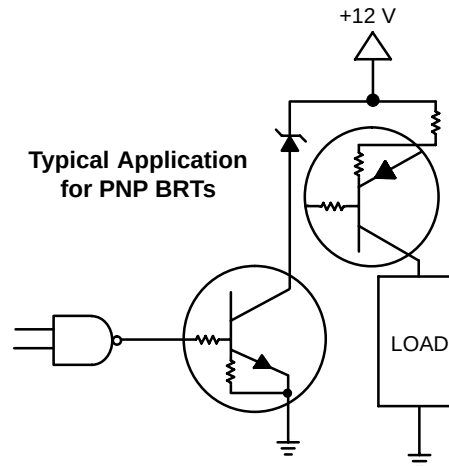


Figure 2. Inexpensive, Unregulated Current Source

MUN2111T1 Series

TYPICAL ELECTRICAL CHARACTERISTICS – MUN2111T1

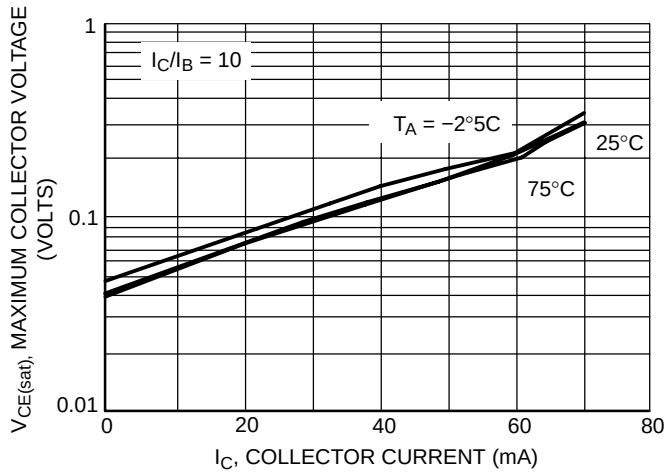


Figure 3. $V_{CE(sat)}$ vs. I_C

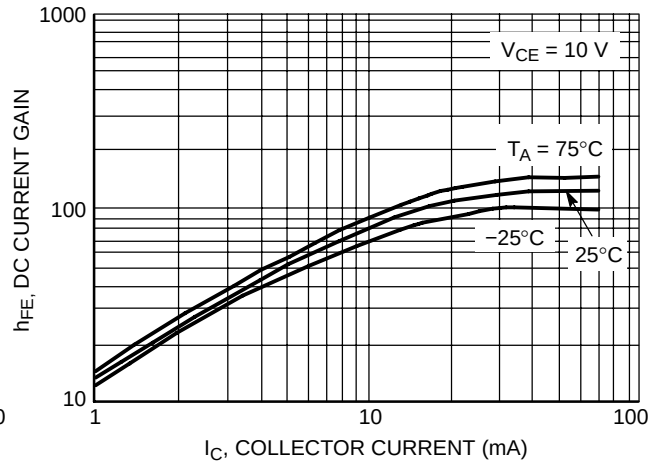


Figure 4. DC Current Gain

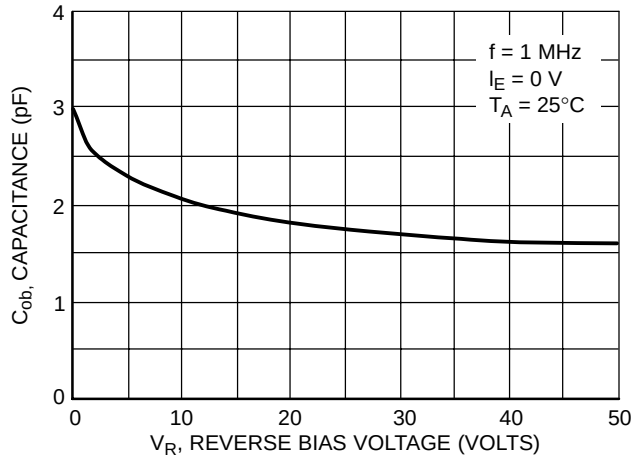


Figure 5. Output Capacitance

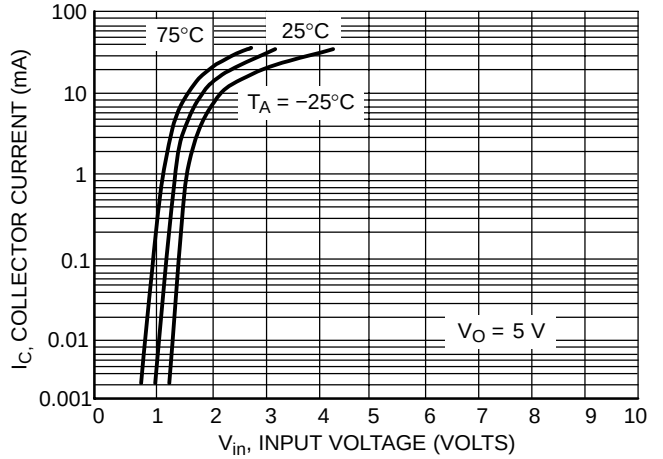


Figure 6. Output Current vs. Input Voltage

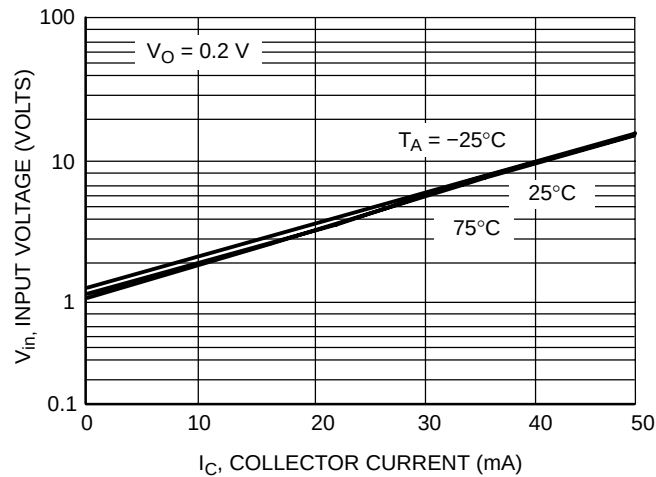


Figure 7. Input Voltage vs. Output Current

TYPICAL ELECTRICAL CHARACTERISTICS – MUN2112T1

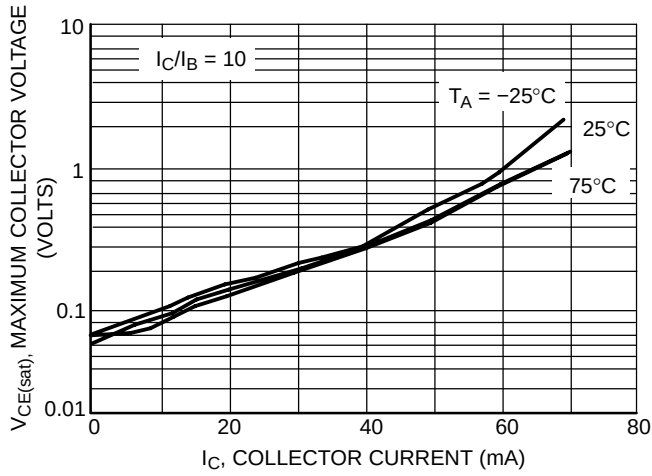


Figure 8. $V_{CE(sat)}$ vs. I_C

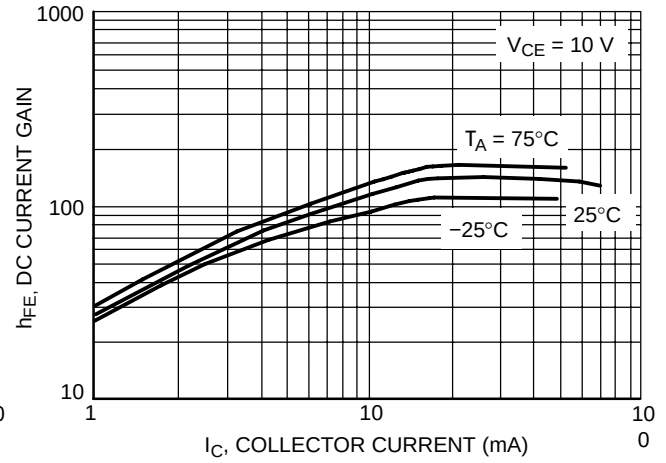


Figure 9. DC Current Gain

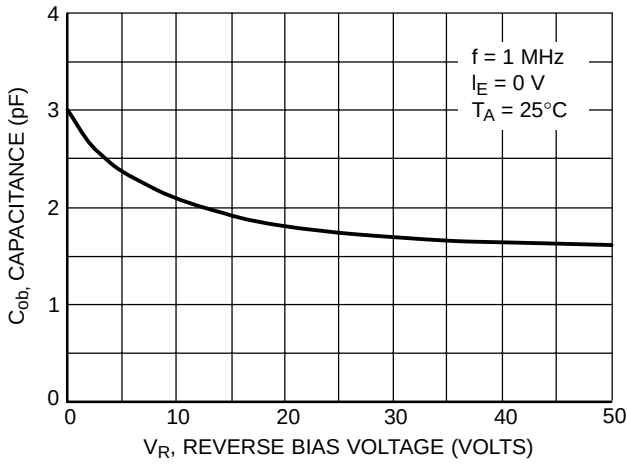


Figure 10. Output Capacitance

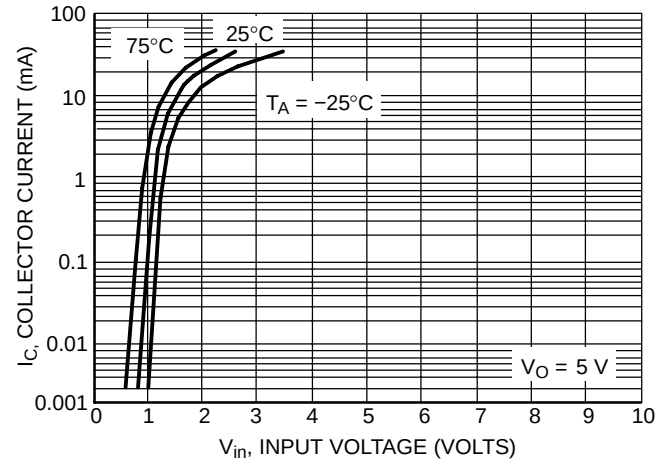


Figure 11. Output Current vs. Input Voltage

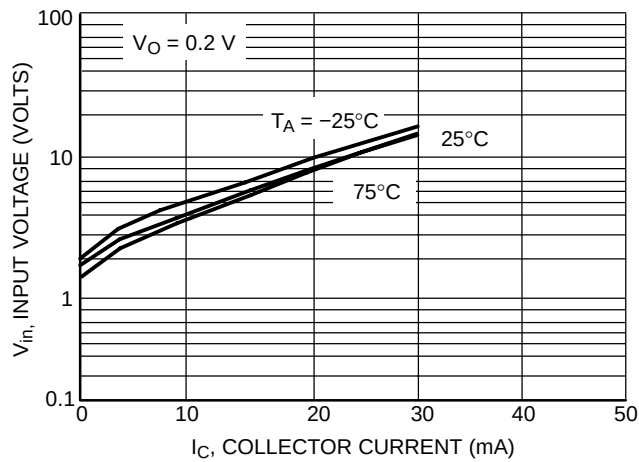


Figure 12. Input Voltage vs. Output Current

MUN2111T1 Series

TYPICAL ELECTRICAL CHARACTERISTICS – MUN2113T1

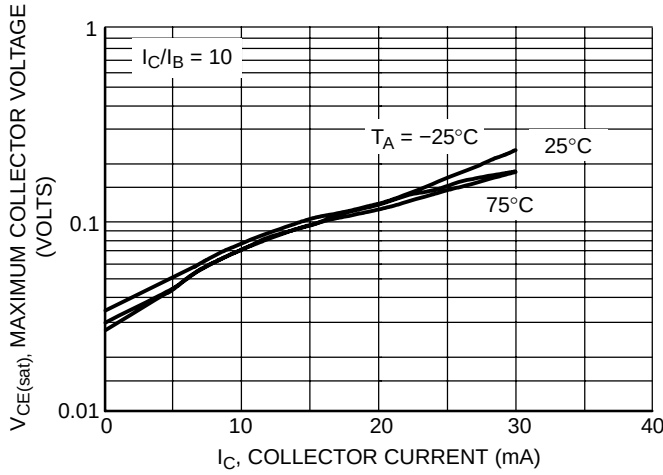


Figure 13. $V_{CE(sat)}$ vs. I_C

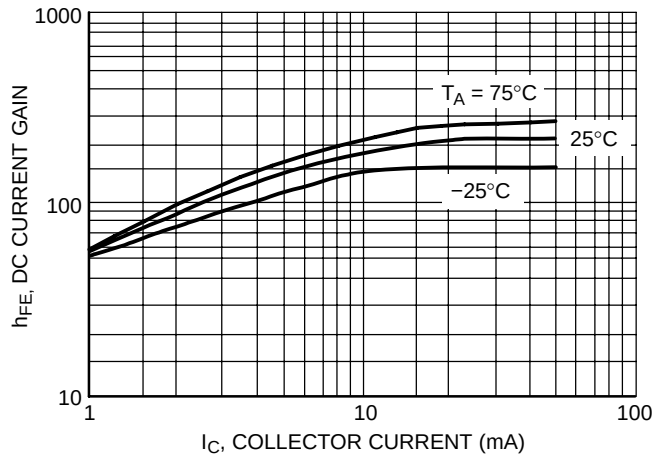


Figure 14. DC Current Gain

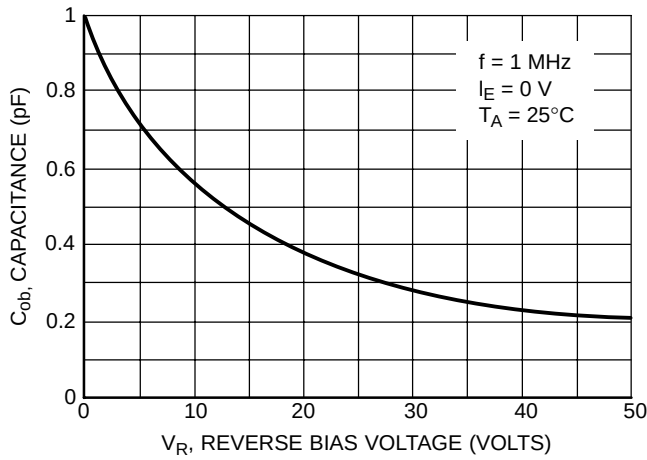


Figure 15. Output Capacitance

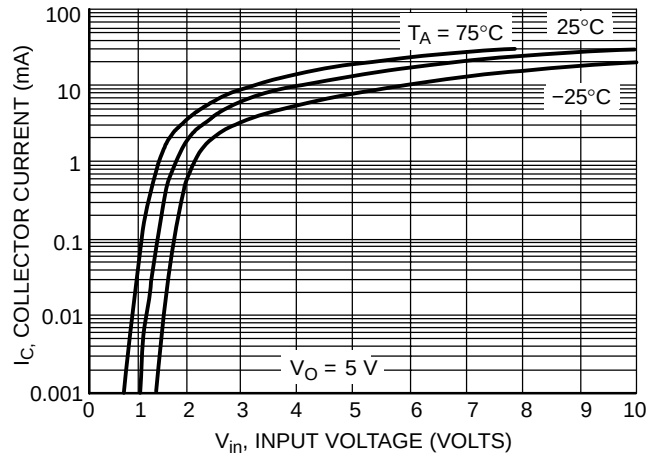


Figure 16. Output Current vs. Input Voltage

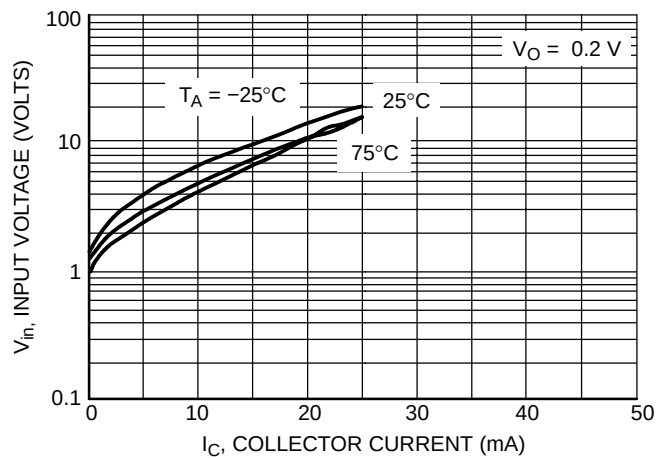


Figure 17. Input Voltage vs. Output Current

MUN2111T1 Series

TYPICAL ELECTRICAL CHARACTERISTICS – MUN2114T1

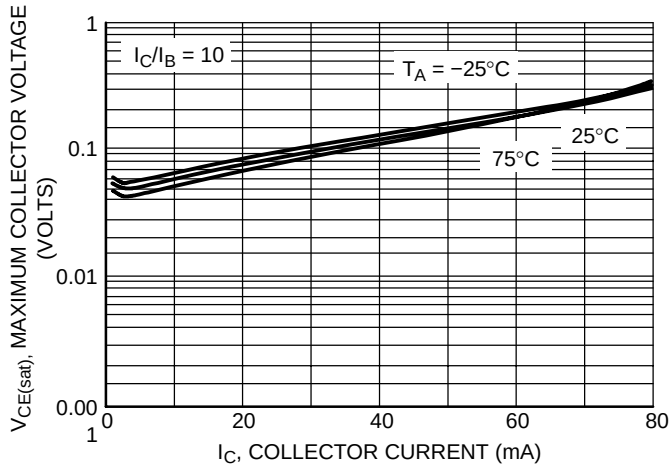


Figure 18. $V_{CE(sat)}$ vs. I_C

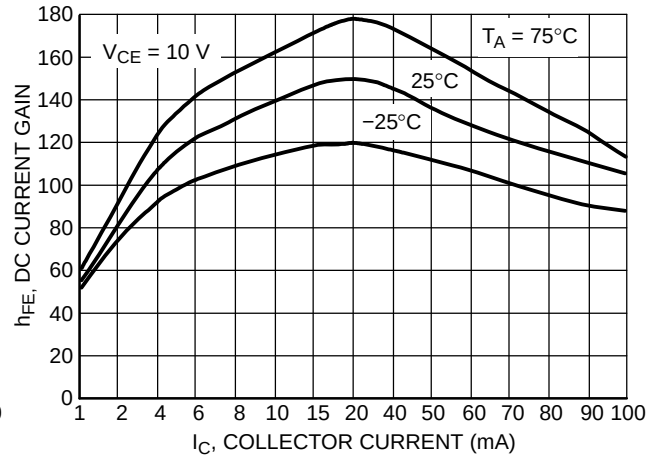


Figure 19. DC Current Gain

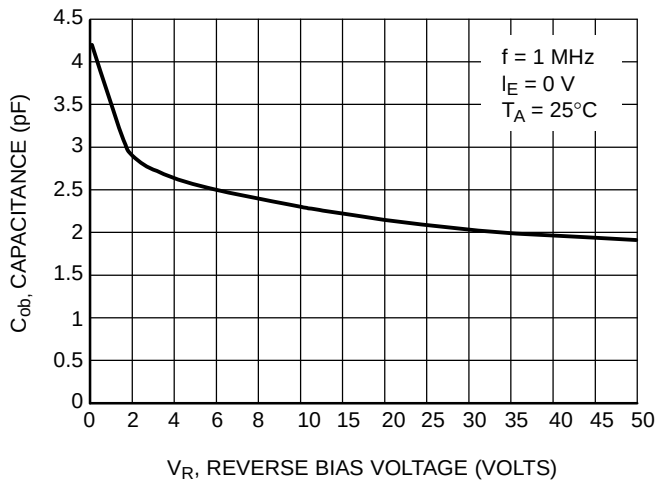


Figure 20. Output Capacitance

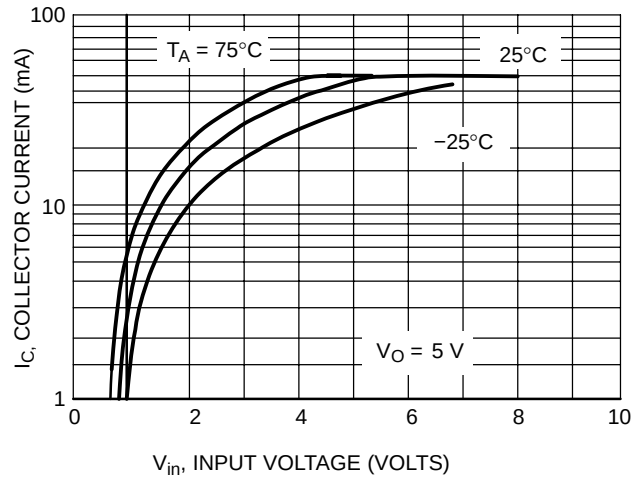


Figure 21. Output Current vs. Input Voltage

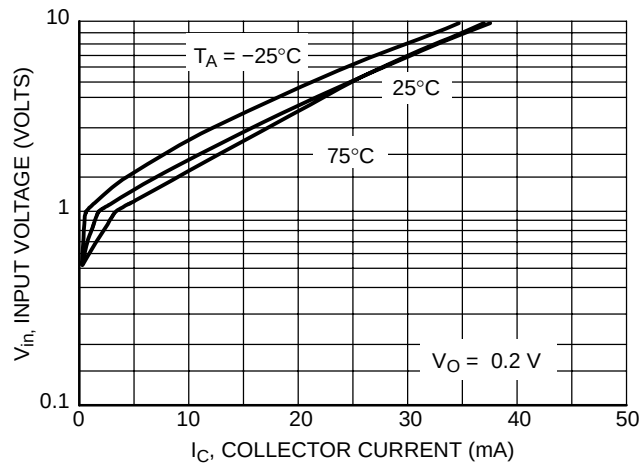


Figure 22. Input Voltage vs. Output Current

TYPICAL ELECTRICAL CHARACTERISTICS – MUN2131T1

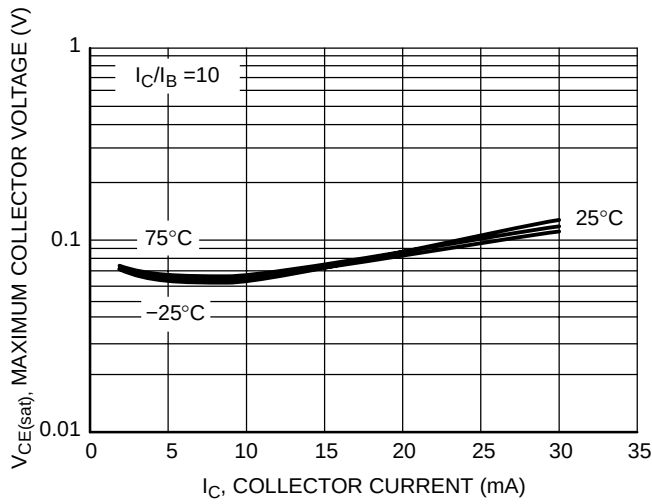


Figure 23. $V_{CE(sat)}$ vs. I_C

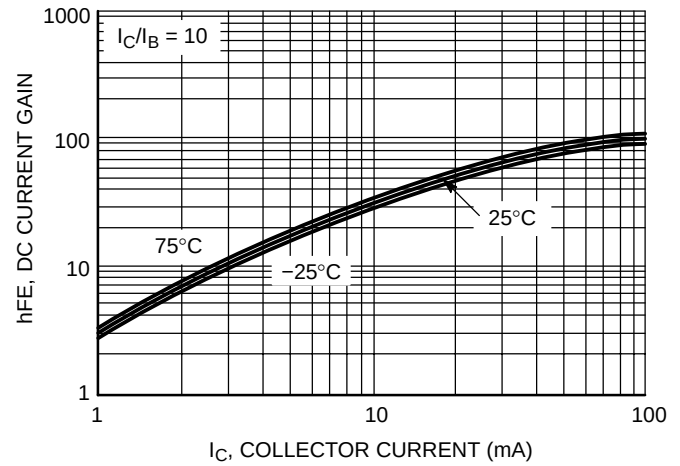


Figure 24. DC Current Gain

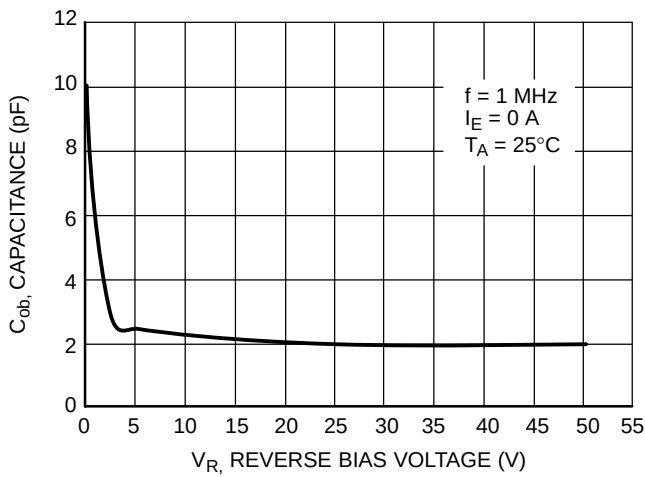


Figure 25. Output Capacitance

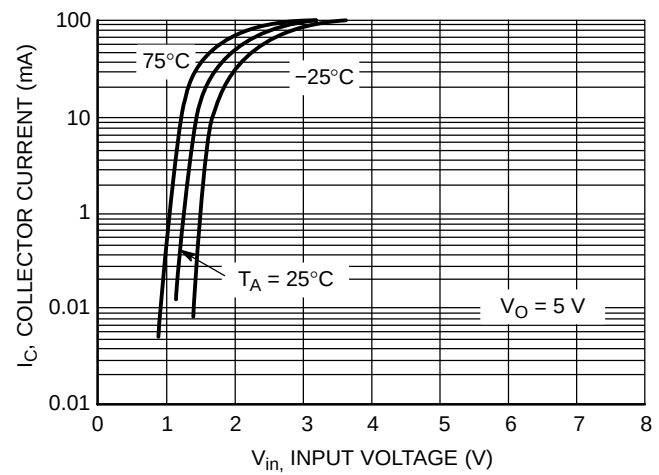


Figure 26. Output Current vs. Input Voltage

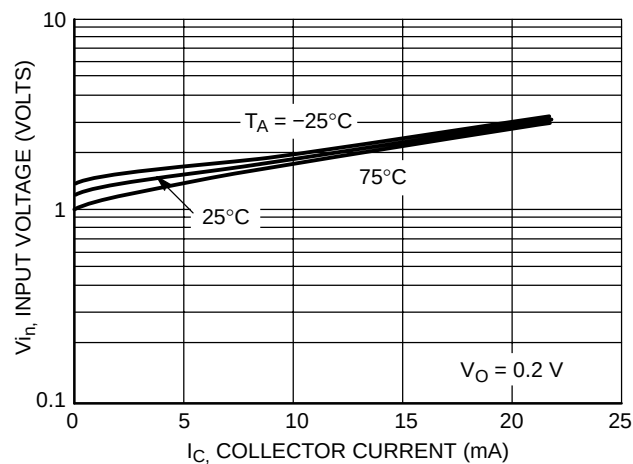


Figure 27. Input Voltage vs. Output Current

TYPICAL ELECTRICAL CHARACTERISTICS — MUN2133T1

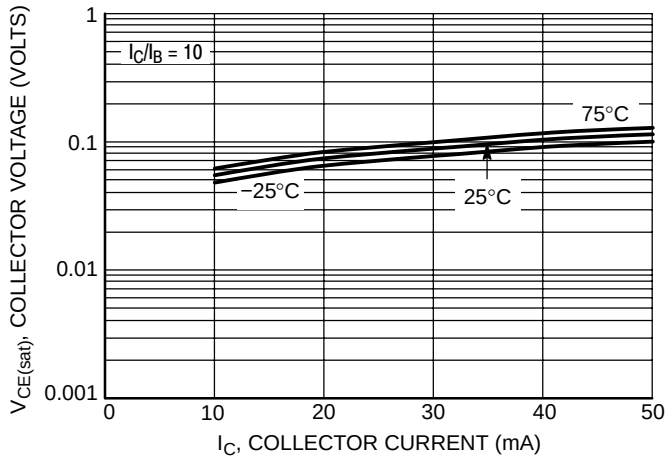


Figure 28. $V_{CE(sat)}$ versus I_C

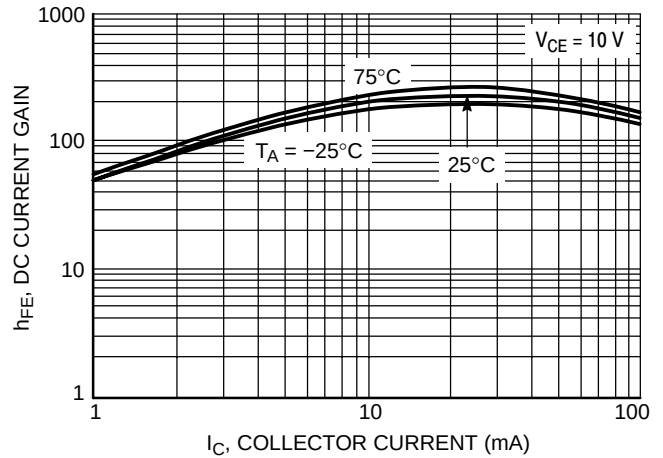


Figure 29. DC Current Gain

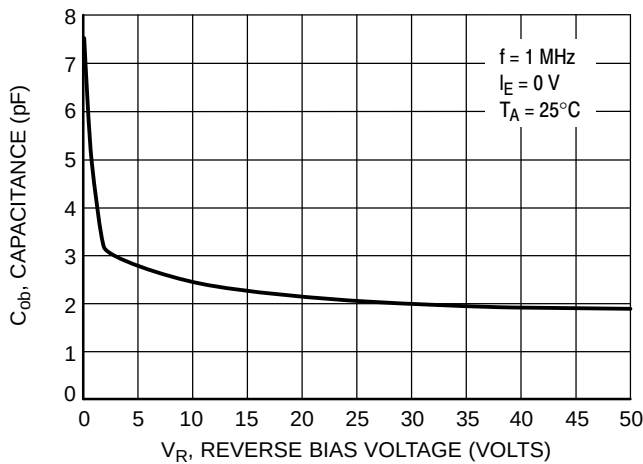


Figure 30. Output Capacitance

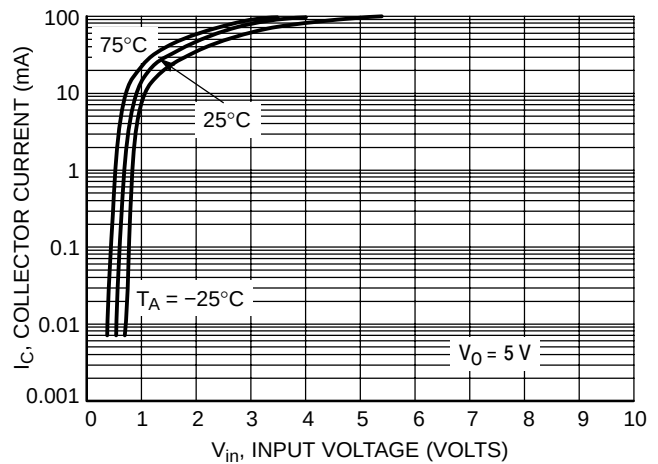


Figure 31. Output Current versus Input Voltage

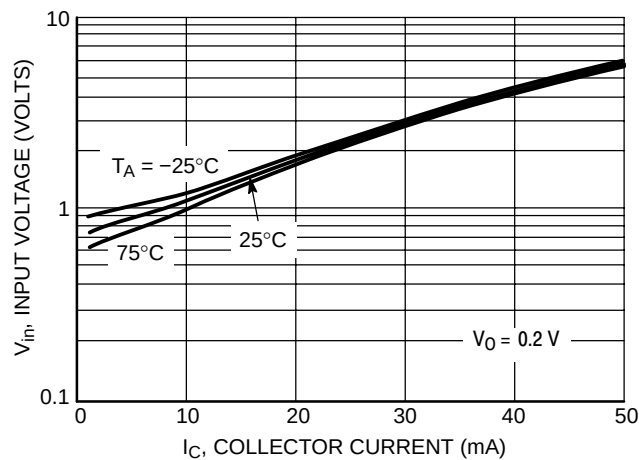


Figure 32. Input Voltage versus Output Current

TYPICAL ELECTRICAL CHARACTERISTICS — MUN2136T1

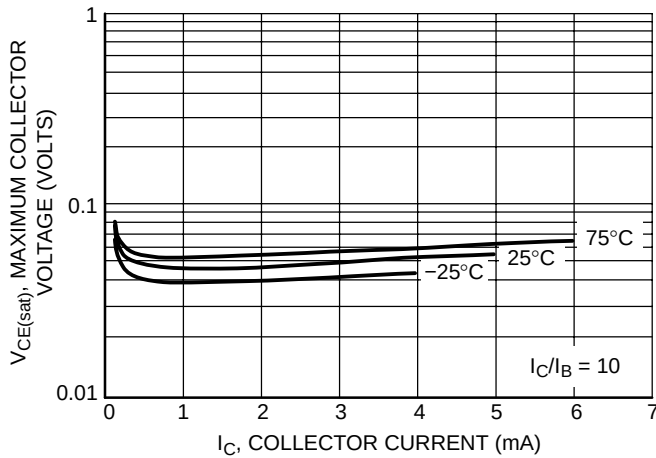


Figure 33. Maximum Collector Voltage vs. Collector Current

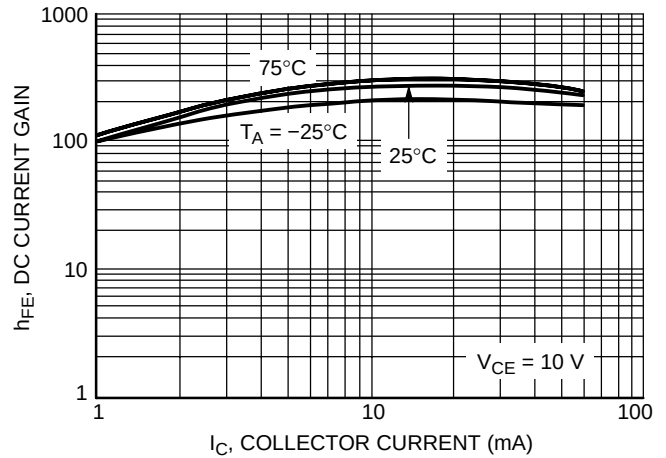


Figure 34. DC Current Gain

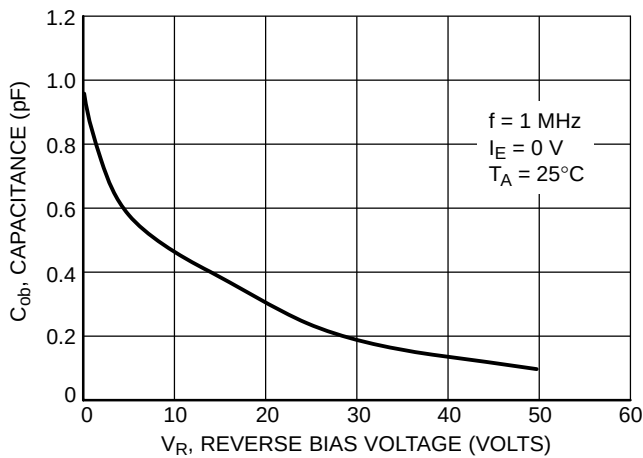


Figure 35. Output Capacitance

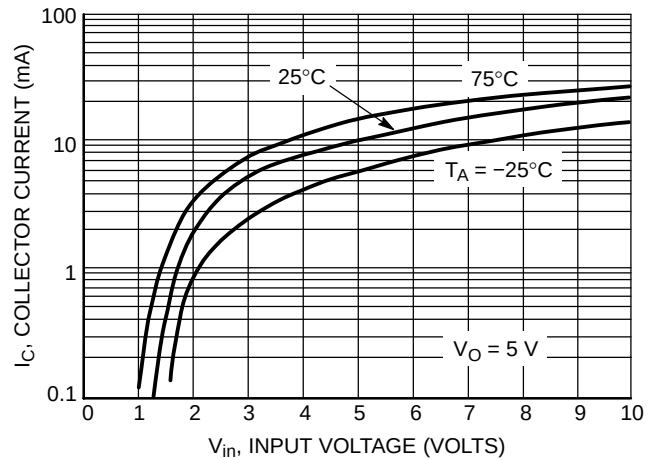


Figure 36. Output Current vs. Input Voltage

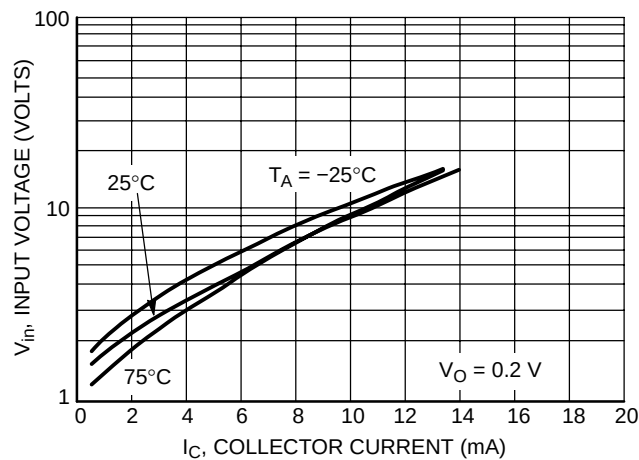


Figure 37. Input Voltage vs. Output Current

TYPICAL ELECTRICAL CHARACTERISTICS — MUN2137T1

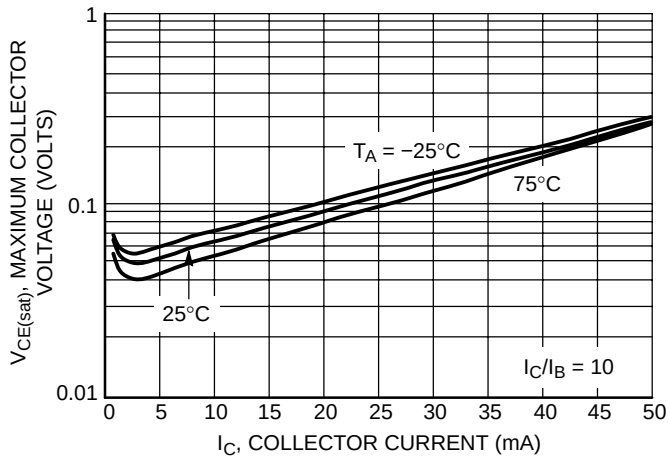


Figure 38. Maximum Collector Voltage vs. Collector Current

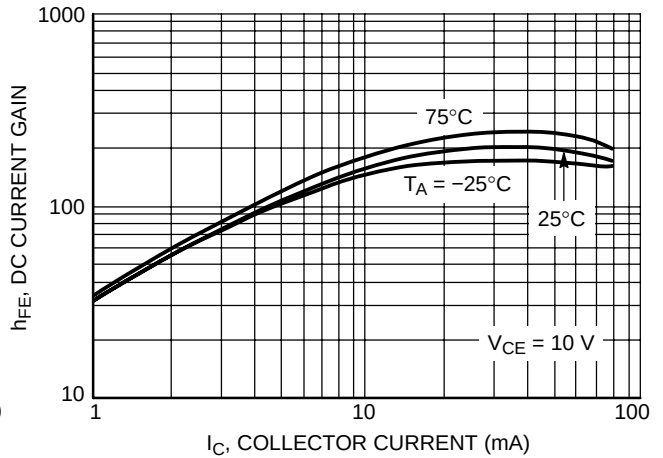


Figure 39. DC Current Gain

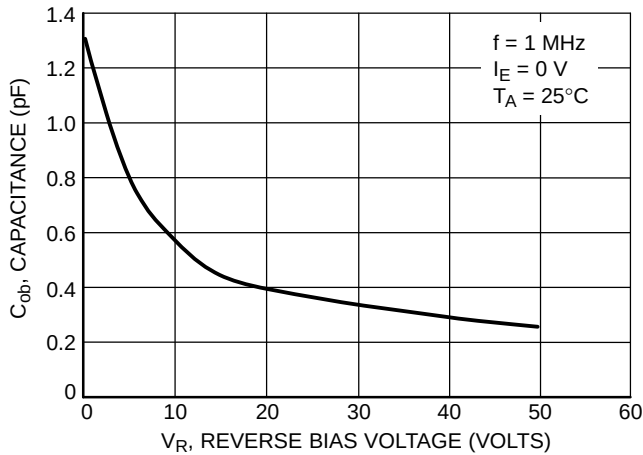


Figure 40. Output Capacitance

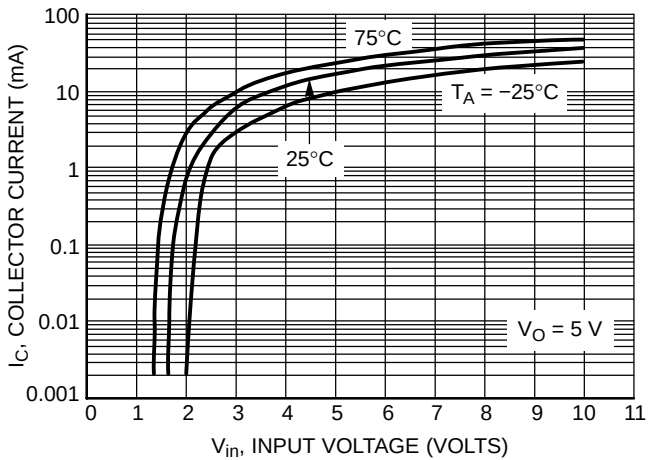


Figure 41. Output Current vs. Input Voltage

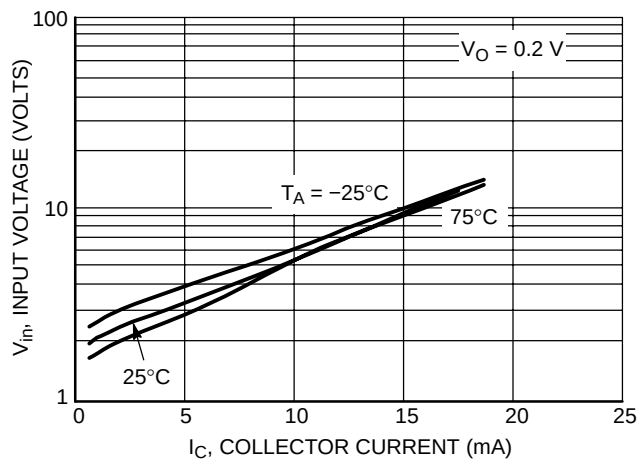
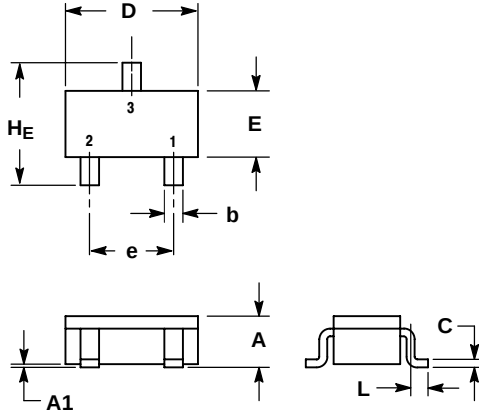


Figure 42. Input Voltage vs. Output Current

MUN2111T1 Series

PACKAGE DIMENSIONS

SC-59
CASE 318D-04
ISSUE G

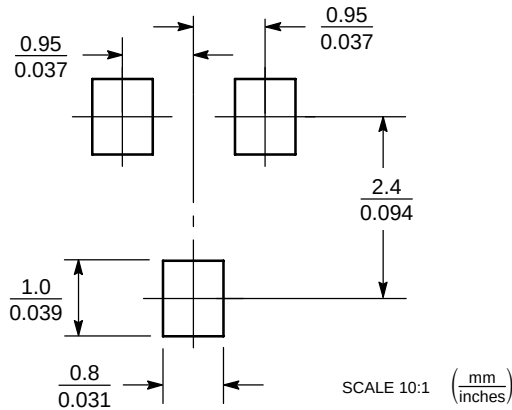


NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	1.00	1.15	1.30	0.039	0.045	0.051
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.35	0.43	0.50	0.014	0.017	0.020
c	0.09	0.14	0.18	0.003	0.005	0.007
D	2.70	2.90	3.10	0.106	0.114	0.122
E	1.30	1.50	1.70	0.051	0.059	0.067
e	1.70	1.90	2.10	0.067	0.075	0.083
L	0.20	0.40	0.60	0.008	0.016	0.024
HE	2.50	2.80	3.00	0.099	0.110	0.118

STYLE 1:
PIN 1. EMITTER
2. BASE
3. COLLECTOR

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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For additional information, please contact your local Sales Representative

Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибьюторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

Мы предлагаем:

- Конкурентоспособные цены и скидки постоянным клиентам.
- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



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